In the Claims:

1. (original) An integrated circuit comprising:

a body bias distribution circuit;

a pad coupled to said body bias distribution circuit, said pad for receiving

an externally applied voltage;

an internal voltage bus; and

a circuit component coupled to said internal voltage bus and coupled to

said body bias distribution circuit, wherein said internal voltage bus supplies a

body bias voltage to said distribution circuit absent a voltage applied to said

pad.

2. (original) An integrated circuit as described in Claim 1 wherein said

externally applied voltage is substantially applied to said distribution circuit

when said externally applied voltage is applied to said pad.

3. (original) An integrated circuit as described in Claim 2 wherein said

circuit component is a resistor element.

4. (original) An integrated circuit as described in Claim 2 further

comprising an external pin coupled to said pad, said external pin for coupling

with said externally supplied voltage.

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5. (original) An integrated circuit as described in Claim 2 wherein said internal voltage bus is coupled to a power supply voltage of said integrated

circuit.

6. (original) An integrated circuit as described in Claim 1 further

comprising a plurality of metal oxide semiconductor transistors coupled to said

body bias distribution circuit.

7. (original) An integrated circuit as described in Claim 6 wherein said

plurality of metal oxide semiconductor transistors are coupled to said

distribution circuit via respective body terminals.

8 – 14 (canceled) (restriction)

15. (original) A semiconductor device comprising a first terminal for coupling

a voltage to a body terminal of a metal oxide semiconductor, wherein said body

terminal is not coupled to a source or a drain of said metal oxide semiconductor.

16. (original) The semiconductor device of Claim 15 wherein said first

terminal is a package pin of a semiconductor package.

17. (original) The semiconductor device of Claim 15 wherein said first

terminal is a pad of an integrated circuit.

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- 18. (original)The semiconductor device of Claim 15 wherein said first terminal is a coupling to a metal layer of said semiconductor device.
- 19. (original)The semiconductor device of Claim 15 wherein said metal oxide semiconductor operates as a digital device.
- 20. (original)The semiconductor device of Claim 15 wherein said semiconductor device comprises a microprocessor.
- 21. (original)The semiconductor device of Claim 15 comprising a plurality of metal oxide semiconductors.
 - 22 34 (canceled) (restriction)
- 35. (original)A method of providing a body bias voltage in a semiconductor device comprising:

responsive to a coupling of an external body bias voltage to said semiconductor device, coupling said body bias voltage to body biasing wells of said semiconductor device; and

responsive to an absence of said external body bias voltage, automatically supplying said body biasing wells of said semiconductor device with an internal voltage of said semiconductor device through a resistance.

36. (original)The method of Claim 35 wherein said internal voltage is a

power supply voltage for said semiconductor device.

37. (original)The method of Claim 35 wherein said internal voltage is a

ground reference for said semiconductor device.

38. (original)The method of Claim 35 wherein said resistive structure

comprises an n well region.

39. (original)The method of Claim 35 wherein said resistive structure forms

a desired resistance between said internal voltage and said n well channels.

40. (original) The method of Claim 39 wherein said desired resistance is

about 1 kilo ohm.

41. (original)The method of Claim 35 wherein said resistance is at least

about one hundred times as large as a resistance of said coupling of said body bias

voltage to said body biasing wells of said semiconductor device.

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